



DMWSH120H28SM3

1200V N-CHANNEL SILICON CARBIDE POWER MOSFET

Product Summary

BV _{DSS}	RDS(ON) Max	I _D Tc = +25°C
1200V	$28.5m\Omega @V_{GS} = 15V$	97.4A

Description and Applications

This SiC MOSFET is designed to minimize the on-state resistance yet maintain superior switching performance, making it ideal for highefficiency power-management applications.

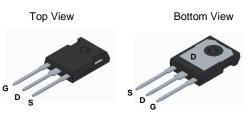
- EV high-power DC-DC converters
- EV charging systems
- AC-DC traction inverters
- Automotive motor drivers

Features and Benefits

- Low On-Resistance
- High BV_{DSS} Rating for Power Application
- Low Input Capacitance
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- An automotive-compliant part is available under separate datasheet (<u>DMWSH120H28SM3Q</u>)

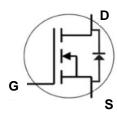
Mechanical Data

- Package: TO247
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 (e3)
- Weight: 5.6 grams (Approximate)



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Pin Configuration



Internal Schematic

Ordering Information (Note 4)

Part Number	Packaga	Packing		
Fait Nulliber	Package	Qty.	Carrier	
DMWSH120H28SM3	TO247 Standard	30 Pieces	Tube	

Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

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D | | = Manufacturer's Marking120H28SM3 = Product Type Marking CodeYYWW or YYWW = Date Code MarkingYY or YY = Last Two Digits of Year (ex: 24 = 2024)WW or WW = Week Code (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	Vdss	1200	V	
Gate-Source Voltage (Dynamic)	Vgss	+19/-8	V	
Gate-Source Voltage (Static)	Vgss	+15/-4	V	
Continuous Drain Current (Notes 5, 6)	T _C = +25°C T _C = +100°C	ID	97.4 68.8	A
Continuous Diode Forward Current (Note 5)	Is	92	A	
Pulsed Source Current (10µs Pulse, Duty Cycle = 1%) (Note 5)	lsм	410	A	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%) (Note 5)	ldм	410	A	

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Tatal Dower Discipation (Nata 5)	Tc = +25°C	D-	405	W	
Total Power Dissipation (Note 5)	Tc = +100°C	PD	203		
Thermal Resistance, Junction to Ambient (Note 7)	R _{0JA}	29	°C/W		
Thermal Resistance, Junction to Case (Note 5)		Rejc	0.37	0.000	
Operating and Storage Temperature Range	TJ, TSTG	-55 to +175	°C		

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)			•		•	-	
Drain-Source Breakdown Voltage	BVDSS	1200			V	$V_{GS} = 0V, I_D = 100 \mu A$	
Zero Gate Voltage Drain Current	IDSS		_	50	μA	V _{DS} = 1200V, V _{GS} = 0V	
Gate-Source Leakage	Igss	_	_	±250	nA	V _{GS} = +15/-4V, V _{DS} = 0V	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	VGS(TH)	1.8	2.5	3.6	V	$V_{DS} = V_{GS}$, $I_D = 17.7 \text{mA}$	
Static Drain-Source On-Resistance	R _{DS(ON)}	_	20	28.5	mΩ	V _{GS} = 15V, I _D = 50A	
Diode Forward Voltage	Vsd	_	3.8	_	V	V _{GS} = -4V, I _S = 25A	
Transconductance	gfs		15	_	S	V _{DS} = 20V, I _D = 50A	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	Ciss	_	3905				
Output Capacitance	Coss		184		pF	Vgs = 0V, Vds = 1000V	
Reverse Transfer Capacitance	Crss		10.2	_		$V_{AC} = 25mV$, f = 1MHz	
Coss Stored Energy	Eoss	—	113	_	μJ		
Turn-On Switching Energy (Body Diode Forward)	Eon	_	742			V _{GS} = -4V/+15V, V _{DS} = 800V	
Turn-Off Switching Energy (Body Diode Forward)	EOFF		363		μJ	R_g = 5 Ω , I_D = 50A, L = 157 μ H	
Gate Resistance	Rg		1.3		Ω	$V_{AC} = 100 \text{mV}, f = 1 \text{MHz}$	
Total Gate Charge	Qg		175				
Gate-Source Charge	Qgs		48.1		nC	V _{GS} = -4V/+15V, V _{DS} = 800V I _D = 50A	
Gate-Drain Charge	Qgd	_	55.3				
Turn-On Delay Time	t _{D(ON)}		24.2			$V_{GS} = -4V/+15V, V_{DD} = 800V$ $R_g = 5\Omega, L = 157\mu H$	
Turn-On Rise Time	tR		40.6		20		
Turn-Off Delay Time	td(off)		44.8		ns		
Turn-Off Fall Time	tF	_	12.8	_			
Body Diode Reverse Recovery Time	t _{RR}		22.5	_	ns		
Body Diode Reverse Recovery Charge	Qrr	_	432	_	nC	V _{GS} = -4V, V _{DS} = 800V I _D = 50A, di/dt = 2600A/µs	
Body Diode Reverse Recovery Current	Irrm	_	30		А	$D = 30A, di/dt = 2000A/\mu s$	

5. Device mounted on an infinite heatsink.

Drain current limited by maximum junction temperature.
 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

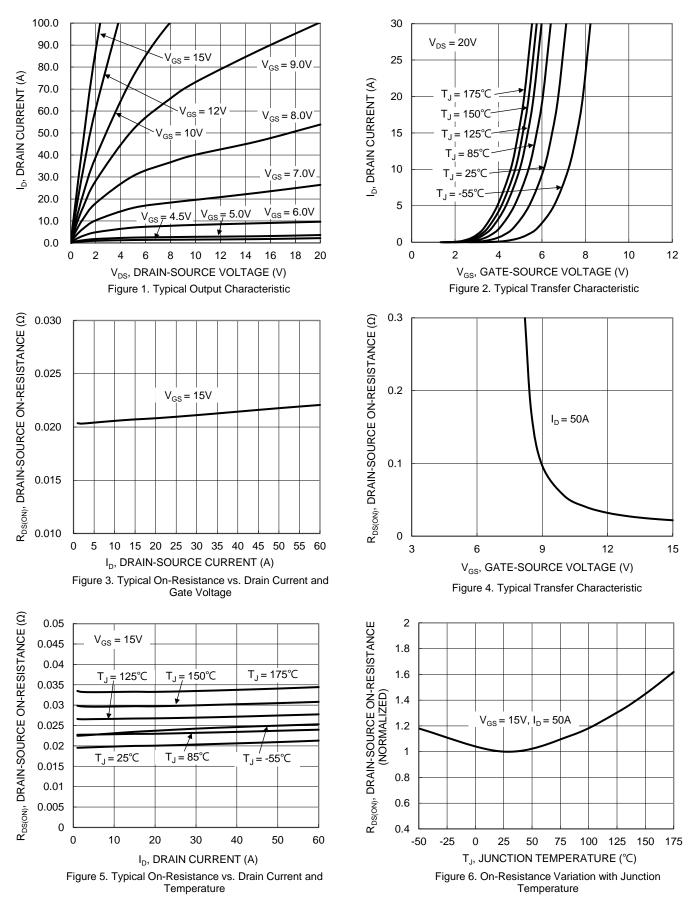
8. Short duration pulse test used to minimize self-heating effect.

9. Guaranteed by design. Not subject to production testing.

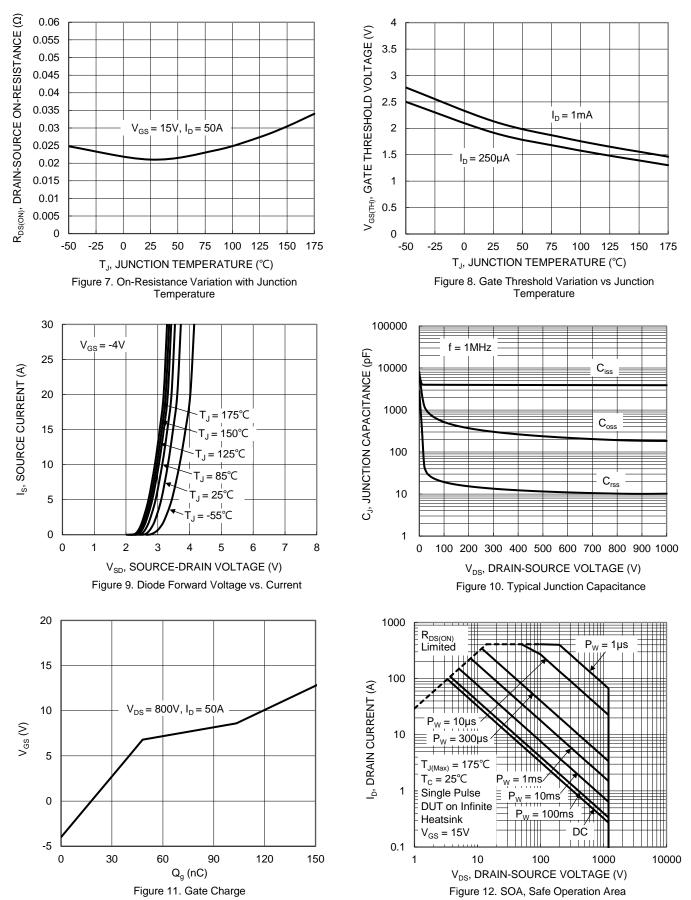
Notes:



DMWSH120H28SM3











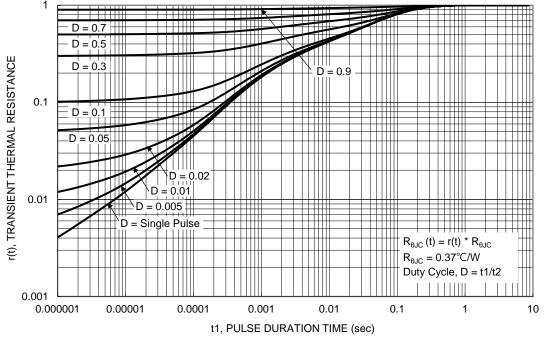
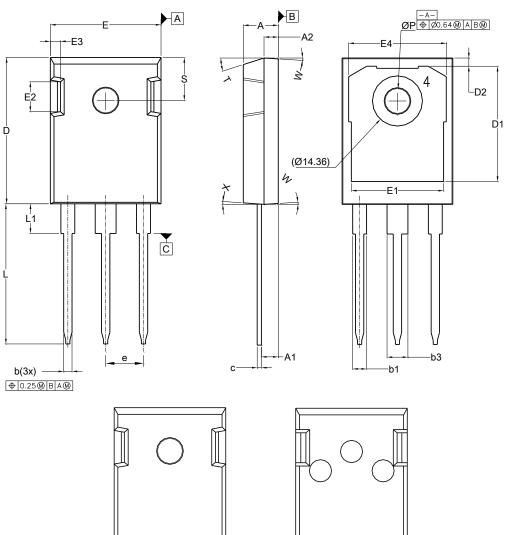


Figure 13. Transient Thermal Resistance

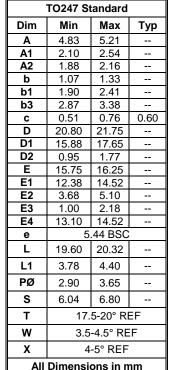


Package Outline Dimensions

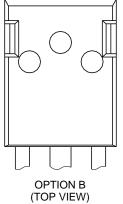
Please see http://www.diodes.com/package-outlines.html for the latest version.



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OPTION A (TOP VIEW)





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